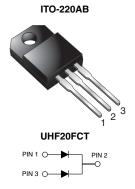
New Product



Vishay General Semiconductor

Dual Common-Cathode Ultrafast Recovery Rectifier



PRIMARY CHARACTERISTICS					
I _{F(peak)}	10 A x 2				
V _{RRM}	300 V				
I _{FSM}	180 A				
t _{rr}	25 ns				
V_F at I_F = 10 A	0.85 V				
T _J max.	175 °C				

FEATURES

- Oxide planar chip junction
- Ultrafast recovery times
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency power factor correctors, switching mode power supplies, freewheeling diodes and secondary dc-to-dc rectification application.

MECHANICAL DATA

Case: ITO-220AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	UHF20FCT	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	300	V		
Maximum DC working forward current at T_C = 125 °C	per device per diode	I _{F(peak)}	20 10	А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	per diode	I _{FSM}	180	А		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500	V		
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to + 175	°C		

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	l _F = 5.0 A l _F = 10.0 A	T _A = 25 °C	V _F	0.96 1.02	- 1.20	v
	l _F = 5.0 A l _F = 10.0 A	T _A = 125 °C		0.77 0.85	-	
Maximum reverse current per diode (2)	V _R = 300 V	T _A = 25 °C T _A = 125 °C	I _R	0.06 25	5 150	μA

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COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	SYMBOL TYP.		UNIT	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$	t _{rr}	20	25	ns	
Maximum reverse recovery time per diode	$ I_{F} = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_{R} = 30 \text{ V}, \text{ I}_{rr} = 0.1 \text{ I}_{RM} $	t _{rr}	28	35	ns	
Typical softness factor (tb/ta)	I _F = 10 A, dl/dt = 200 A/μs,	S	0.36	-	-	
Typical reverse recovery current	$V_{R} = 200 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$	I _{RM}	7.0	-	А	
Typical stored charge	per diode	Q _{rr}	160	-	nC	
Typical forward recovery time per diode	$I_F = 10 \text{ A}, \text{ dl/dt} = 80 \text{ A/}\mu\text{s},$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax}$	t _{fr}	150	-	ns	

Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UHF20FCT	UNIT		
Typical thermal resistance per diode	${{R}_{{\theta JA}}}^{(1)}_{{{R}_{{\theta JC}}}^{(2)}}$	50 4.6	°C/W		

Notes:

(1) Without heatsink, free air

(2) With infinite heatsink

ORDERING INFORMATION (Example)							
PACKAGE	AGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVER				DELIVERY MODE		
ITO-220AB	UHF20FCT-E3/4W	1.74	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

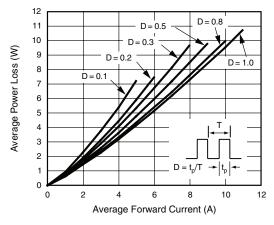


Figure 1. Forward Power Loss Characteristics Per Diode

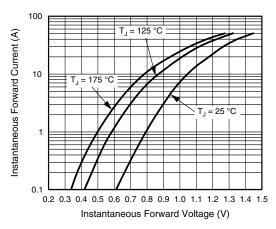


Figure 2. Typical Instantaneous Forward Characteristics Per Diode



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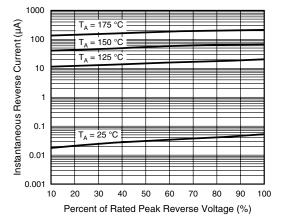


Figure 3. Typical Reverse Leakage Characteristics Per Diode

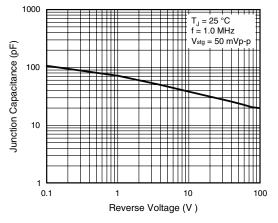
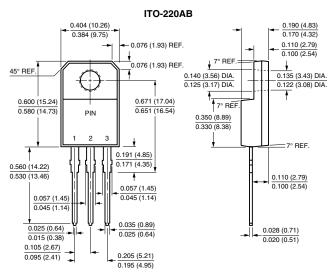


Figure 4. Typical Junction Capacitance Per Diode





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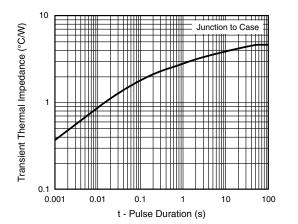


Figure 5. Typical Transient Thermal Impedance Per Diode



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